



U74AHC3G14

CMOS IC

INVERTING SCHMITT TRIGGER

DESCRIPTION

The **U74AHC3G14** is a high-speed inverting Schmitt trigger.

The **U74AHC3G14** provides three inverting buffers with the action of Schmitt trigger. The trigger is capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

FEATURES

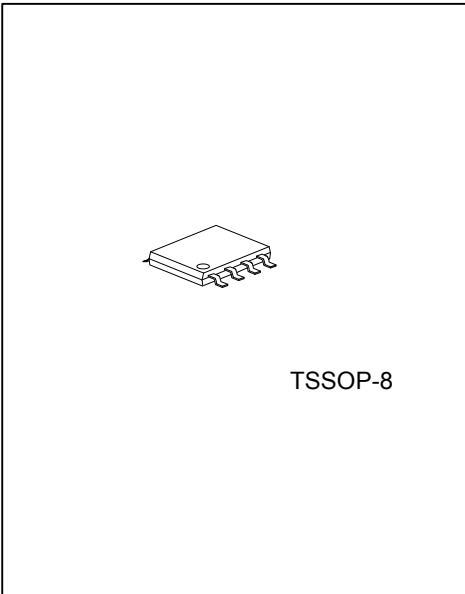
- * Low power supply 1.0 μ A at 5.5V
- * Wide supply voltage range from 2V to 5.5V
- * Up to 5.5V inputs accept voltages
- * Max t_{PD} of 8.6 ns at $V_{CC} = 5.0V$, $C_L = 15pF$
- * Symmetrical output impedance
- * High noise immunity
- * Balanced propagation delays

APPLICATION

- * Astable multivibrators
- * Monostable multivibrators
- * Wave and pulse shapers

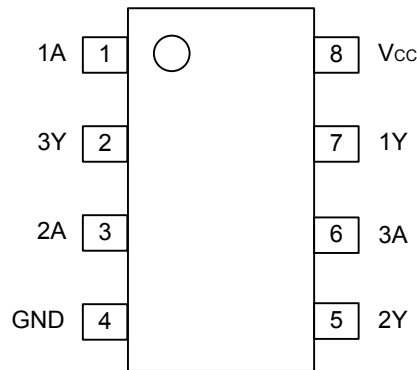
ORDERING INFORMATION

| Ordering Number | | Package | Packing |
|-------------------|-------------------|---------|-----------|
| Lead Free | Halogen Free | | |
| U74AHC3G14L-P08-R | U74AHC3G14G-P08-R | TSSOP-8 | Tape Reel |
| U74AHC3G14L-P08-T | U74AHC3G14G-P08-T | TSSOP-8 | Tube |



| | |
|--|---|
| <p>U74AHC3G14L-P08-T</p> <p>(1)Packing Type (2)Package Type (3)Lead Free</p> | <p>(1) R: Tape Reel, T: Tube (2) P08: TSSOP-8 (3) G: Halogen Free, L: Lead Free</p> |
|--|---|

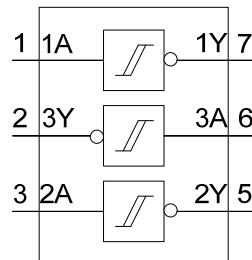
■ PIN CONFIGURATION



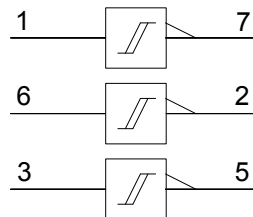
■ FUNCTION TABLE

| INPUT | OUTPUT |
|-------|--------|
| nA | nY |
| L | H |
| H | L |

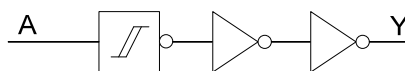
■ LOGIC SYMBOL



■ IEC LOGIC SYMBOL



■ LOGIC DIAGRAM (one driver)



■ ABSOLUTE MAXIMUM RATING (unless otherwise specified)

| PARAMETER | SYMBOL | RATINGS | UNIT |
|---|-----------|-------------|-------------|
| Supply Voltage | V_{CC} | -0.5~7.0 | V |
| Input Voltage | V_{IN} | -0.5~7.0 | V |
| Output Voltage | V_{OUT} | 0~ V_{CC} | V |
| Input Diode Current ($V_I < -0.5V$) | I_{IK} | -20 | mA |
| Output Diode Current ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) | I_{OK} | ± 20 | mA |
| Output source or sink current ($-0.5V < V_O < V_{CC} + 0.5V$) | I_{OUT} | ± 25 | mA |
| V_{CC} or GND Current | I_{CC} | ± 75 | mA |
| Power Dissipation | P_D | 250 | mW |
| Storage Temperature | T_{STG} | -65 ~ +150 | $^{\circ}C$ |

Note: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ RECOMMENDED OPERATING CONDITIONS

| PARAMETER | SYMBOL | MIN | TYP | MAX | UNIT |
|-----------------------|----------|-----|-----|----------|-------------|
| Supply Voltage | V_{CC} | 2.0 | 5.0 | 5.5 | V |
| Input Voltage | V_I | 0 | | 5.5 | V |
| Output Voltage | V_O | 0 | | V_{CC} | |
| Operating Temperature | T_A | -40 | +25 | +125 | $^{\circ}C$ |

■ ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$, unless otherwise specified)

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---------------------------|---------------|--|------|-----|------|---------|
| High-Level Output Voltage | V_{OH} | $I_{OH} = -50 \mu A, V_{CC} = 2.0V$ | 1.9 | 2.0 | | V |
| | | $I_{OH} = -50 \mu A, V_{CC} = 3.0V$ | 2.9 | 3.0 | | |
| | | $I_{OH} = -50 \mu A, V_{CC} = 4.5V$ | 4.4 | 4.5 | | |
| | | $I_{OH} = -4.0 mA, V_{CC} = 3.0V$ | 2.58 | | | |
| | | $I_{OH} = -8.0 mA, V_{CC} = 4.5V$ | 3.94 | | | |
| Low-Level Output Voltage | V_{OL} | $I_{OH} = 50 \mu A, V_{CC} = 2.0V$ | | 0 | 0.1 | V |
| | | $I_{OH} = 50 \mu A, V_{CC} = 3.0V$ | | 0 | 0.1 | |
| | | $I_{OH} = 50 \mu A, V_{CC} = 4.5V$ | | 0 | 0.1 | |
| | | $I_{OH} = 4.0 mA, V_{CC} = 3.0V$ | | | 0.36 | |
| | | $I_{OH} = 8.0 mA, V_{CC} = 4.5V$ | | | 0.36 | |
| Input Leakage Current | $I_{I(LEAK)}$ | $V_{IN} = V_{CC}$ or GND, $V_{CC} = 5.5V, I_{OUT} = 0 A$ | | | 0.1 | μA |
| Quiescent Supply Current | I_{CC} | $V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$ | | | 1.0 | μA |
| Input Capacitance | C_{IN} | | | 1.5 | 10 | pF |

■ TRANSFER CHARACTERISTICS ($T_A = 25^{\circ}C$, unless otherwise specified)

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------------------|----------|-----------------|------|-----|------|------|
| Positive-Going Threshold | V_{T+} | $V_{CC} = 3.0V$ | | - | 2.2 | V |
| | | $V_{CC} = 4.5V$ | | - | 3.15 | |
| | | $V_{CC} = 5.5V$ | | - | 3.85 | |
| Negative-Going Threshold | V_{T-} | $V_{CC} = 3.0V$ | 0.9 | - | | V |
| | | $V_{CC} = 4.5V$ | 1.35 | - | | |
| | | $V_{CC} = 5.5V$ | 1.65 | - | | |
| Hysteresis ($V_{T+} - V_{T-}$) | V_H | $V_{CC} = 3.0V$ | 0.3 | - | 1.2 | V |
| | | $V_{CC} = 4.5V$ | 0.4 | - | 1.4 | |
| | | $V_{CC} = 5.5V$ | 0.5 | - | 1.6 | |

■ AC CHARACTERISTICS ($T_A = 25^\circ\text{C}$, $\text{GND} = 0\text{V}$, $t_R = t_F \leq 3.0 \text{ ns}$)

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---|-----------------------------------|--|-----|-----|------|------|
| Propagation Delay from Input (nA) to Output (nY) | t_{PLH}/t_{PHL} (t_{PD}) | $V_{CC} = 3.3\text{V}$, $C_L = 15\text{pF}$ | | 4.2 | | ns |
| | | $V_{CC} = 3.3\text{V}$, $C_L = 50\text{pF}$ | | 6.0 | | |
| | | $V_{CC} = 3.0 \text{ to } 3.6\text{V}$, $C_L = 15\text{pF}$ | | | 12.8 | |
| | | $V_{CC} = 3.0 \text{ to } 3.6\text{V}$, $C_L = 50\text{pF}$ | | | 16.3 | |
| | | $V_{CC} = 5.0\text{V}$, $C_L = 15\text{pF}$ | | 3.2 | | |
| | | $V_{CC} = 5.0\text{V}$, $C_L = 50\text{pF}$ | | 4.6 | | |
| | | $V_{CC} = 4.5 \text{ to } 5.5\text{V}$, $C_L = 15\text{pF}$ | | | 8.6 | |
| | | $V_{CC} = 4.5 \text{ to } 5.5\text{V}$, $C_L = 50\text{pF}$ | | | 10.6 | |

■ OPERATING CHARACTERISTICS ($T_A = 25^\circ\text{C}$)

| PARAMETER | SYMBOL | TEST CONDITIONS | TYP | UNIT |
|--|----------|---|-----|------|
| Power dissipation capacitance per gate | C_{PD} | $C_L = 15 \text{ pF}$, $f = 10\text{MHz}$ (Note1, 2) | 7.5 | pF |

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in Volts;

N = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

2. The condition is $V_I = \text{GND}$ to V_{CC} .

■ WAVEFORMS

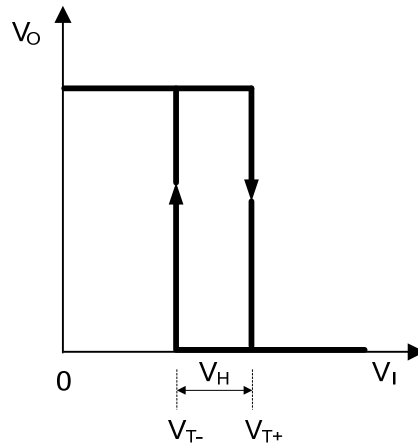


Fig.1 Transfer characteristic

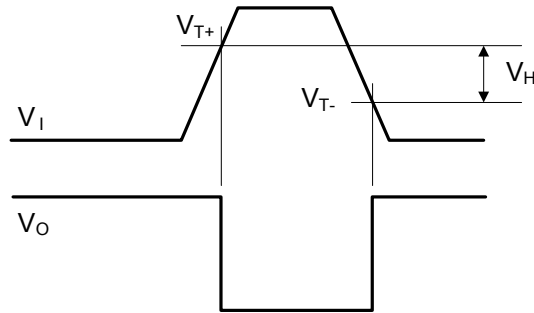
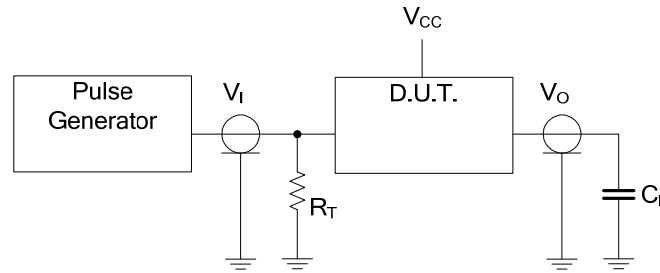


Fig.2 Definitions of V_{T+} , V_{T-} and V_H

■ TEST CIRCUIT AND WAVEFORMS

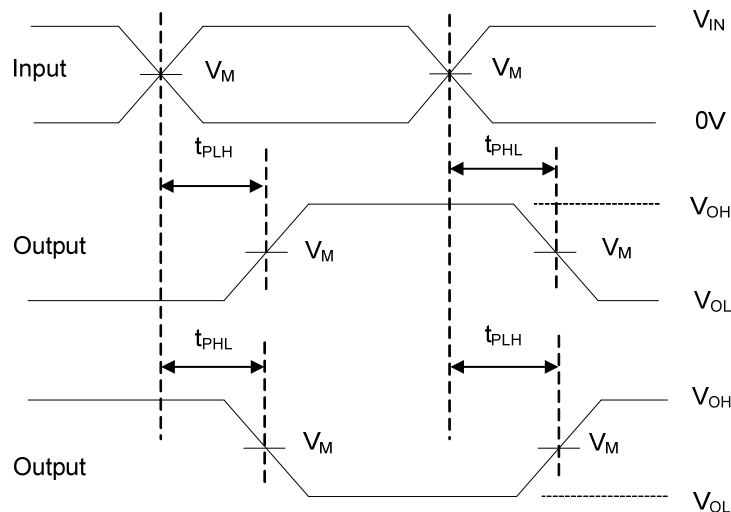


Definitions for test circuit:

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to the output impedance Z_O of the pulse generator.

| V_{CC} | Inputs | | V_M | C_L |
|-------------|-----------------|------------|------------|-------|
| | V_{IN} | t_R, t_F | | |
| 3.3V | GND to V_{CC} | $\leq 3ns$ | $V_{CC}/2$ | 15pF |
| | GND to V_{CC} | $\leq 3ns$ | $V_{CC}/2$ | 50pF |
| 3.0 to 3.6V | GND to V_{CC} | $\leq 3ns$ | $V_{CC}/2$ | 15pF |
| | GND to V_{CC} | $\leq 3ns$ | $V_{CC}/2$ | 50pF |
| 5.0V | GND to V_{CC} | $\leq 3ns$ | $V_{CC}/2$ | 15pF |
| | GND to V_{CC} | $\leq 3ns$ | $V_{CC}/2$ | 50pF |
| 4.5 to 5.5V | GND to V_{CC} | $\leq 3ns$ | $V_{CC}/2$ | 15pF |
| | GND to V_{CC} | $\leq 3ns$ | $V_{CC}/2$ | 50pF |



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